

SANYO Semiconductors **DATA SHEET**

LA6548ND—

Four-Channel Driver IC For CD Players and Recorders Four-Channel Driver IC

Overview

The LA6548ND is a four-channel driver IC for CD players and recorders (four BTL amplifier channels).

Functions

- Four BTL connection power amplifier channels
- IO max 0.7A
- Built-in level shifters
- Muting circuit (on/off control of all outputs)
 (This circuit applies to the BTL amplifier circuits. It does not control operation of the regulator.)
- Built-in regulator (provides a 3.3V output using an external pnp transistor)
- Thermal protection circuit (thermal shutdown circuit)

Specifications

Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC} max		14	V
Maximum output current	I _O max	For each of the channel 1 to 4 outputs	0.7	Α
Maximum input voltage	VIN		13	V
Muting pin application voltage	VMUTE		13	V
Allowable power dissipation	Pd max		1.5	W
Operating temperature	Topr		-20 to +75	°C
Storage temperature	Tstg		-55 to +150	°C

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Recommended Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage 1	V _{CC} 1		4.6 to 13	V
Supply voltage 2 V _{CC} 2		Only used by the BTL amplifiers	3.9 to 13	V
		(Not used by the 3.3V regulator circuit)		

Electrical Characteristics at $Ta = 25^{\circ}C$, $V_{CC}1 = V_{CC}2 = 6V$, VREF = 1.65V, unless otherwise specified.

Demonstra	O make al	O and Hillians	Ratings			11.7	
Parameter	Symbol	Symbol Conditions		typ	max	Unit	
Overall Characteristics							
No-load current drain, on state	I _{CC} ON	All outputs on, MUTE : high		20	40	mA	
No-load current drain, off state	I _{CC} OFF	All outputs off, MUTE : low		15	35	mA	
Thermal shutdown circuit operating temperature	TSD	(Design guarantee value *1)	150	175	200	°C	
Output Amplifier Block							
Output offset voltage	VOFF	The voltage difference between each of the + or - outputs.	-50		50	mV	
VREF input voltage range	V _{IN} VREF		1.3		V _{CC} -1.5	V	
Output voltage	Vo	The voltage across the outputs when $R_L = 8\Omega \label{eq:RL}$	2.6	3		V	
Voltage gain, input to output	VG	The voltage gain from an input to the corresponding +/- outputs.*2		9		dB	
Slew rate	SR	(Design guarantee value *1)		0.15		V/μs	
Muting on voltage	VMUTE	The voltage at which the output on/off state changes		1.2		V	
Power Supply Block (Using a 2S	B632K)						
3.3V power supply voltage		I _O = 200mA	3.13	3.3	3.47	V	
Line regulation	ΔV _O LIN	4.6V ≤ V _{CC} ≤ 12V		40	100	mV	
Load regulation	ΔV _O LOAD	5mA ≤ I _O ≤ 200mA		50	150	mV	
Reset Block			•		'		
RESET pin high-level voltage	V _O RH		3.08	3.25	3.42	V	
RESET pin low-level voltage	V _O RL	ISRL = 2mA, Cd-GND		100	200	mV	
RESET pin threshold voltage	V _{RT}	*4		2.8		V	
RESET pin hysteresis	V _{HYS}	*5	40	80	160	mV	
RESET pin output delay time	td	Cd = 0.1μF		10		ms	

 $^{^{\}star}1$: These parameters are not tested.

 $^{^{\}star}2$: The gain from input to output when only the $V_{\mbox{\footnotesize{IN}}}{}^{\star}$ pins are used.

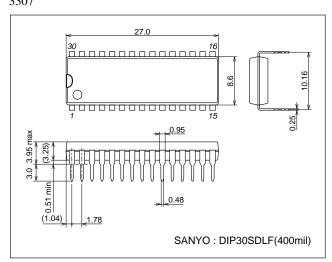
^{*3:} The MUTE pin voltage when the output changes between the on and off states. When the MUTE pin is high, all the BTL amplifiers will be on, and the when MUTE is low, all the BTL amplifiers will be off.

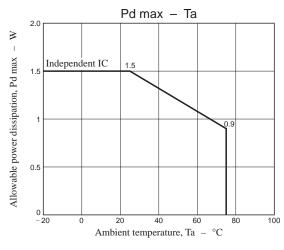
^{*4 :} The 3.3V regulator voltage when the RESET pin goes from high to low.

^{*5 :} The 3.3V regulator voltage difference between the RESET pin going from high to low the RESET pin going from low to high. That is, the hysteresis.

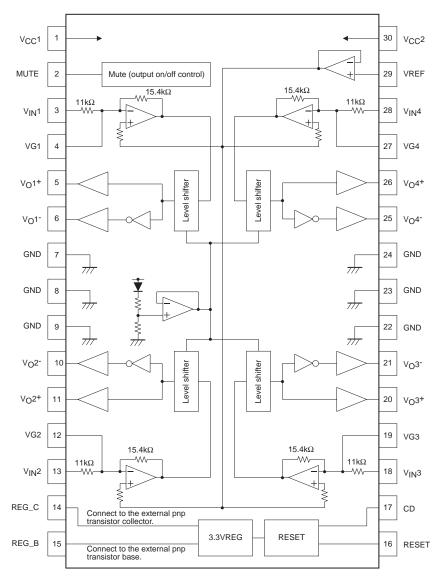
Package Dimensions

unit : mm (typ) 3307





Block Diagram



LA6548ND

Pin Functions

Pin No.	Pin	Description	
1	V _{CC} 1	Power supply (This pin is shorted to V _{CC} 2 (pin 30)	
2	MUTE	Output on/off control	
3	V _{IN} 1	Channel 1 input	
4	VG1	Channel 1 input (Gain setting)	
5	V _O 1+	Channel 1 output (+)	
6	V _O 1⁻	Channel 1 output (-)	
7	GND	GND pin	
8	GND	GND pin	
9	GND	GND pin	
10	V _O 2 ⁻	Channel 2 output (-)	
11	V _O 2+	Channel 2 output (+)	
12	VG2	Channel 2 input (Gain setting)	
13	V _{IN} 2	Channel 2 input	
14	REG_C	Connect this pin to the external pnp transistor collector. (This is the 3.3V regulator output)	
15	REG_B	Connect this pin to the external pnp transistor base.	
16	RESET	Reset output	
17	CD	Connection for the reset delay time setting capacitor	
18	V _{IN} 3	Channel 3 input	
19	VG3	Channel 3 input (Gain setting)	
20	V _O 3+	Channel 3 output (+)	
21	V _O 3-	Channel 3 output (-)	
22	GND	GND pin	
23	GND	GND pin	
24	GND	GND pin	
25	V _O 4 ⁻	Channel 4 output (-)	
26	V _O 4+	Channel 4 output (+)	
27	VG4	Channel 4 input (Gain setting)	
28	V _{IN} 4	Channel 4 input	
29	VREF	Reference voltage input	
30	V _{CC} 2	Power supply (This pin is shorted to V _{CC} 1 (pin 1)	

Equivalent Circuits

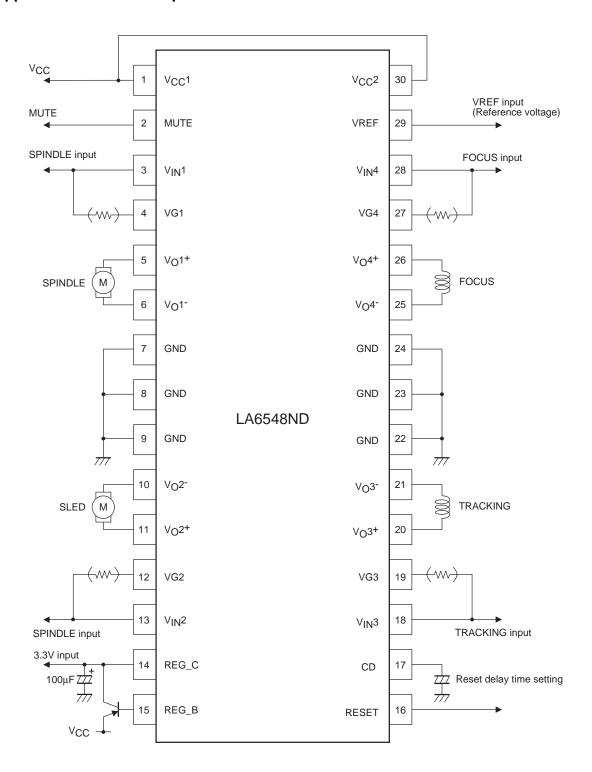
Pin No.	Pin	Description	Equivalent circuit
3	V _{IN} 1	Input pins.	VG* V _{IN} *
4	VG1		() ()
13	V _{IN} 2		
12	VG2		
18	V _{IN} 3		GND GND Ş
19	VG3		
28	V _{IN} 4		
27	VG4		

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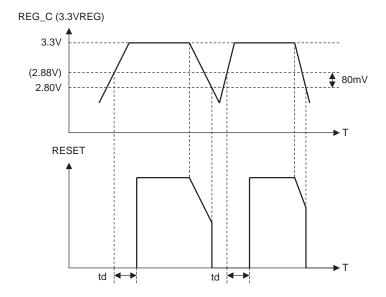
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Pin No.	Pin	Description	Equivalent circuit
5 6 11 10 20	V _O 1+ V _O 1- V _O 2+ V _O 2- V _O 3+	Output pins.	Vcc O
21 26 25	V _O 3 ⁻ V _O 4 ⁺ V _O 4 ⁻		GND VCC
2	MUTE	Muting control input. The outputs will be on when the MUTE pin is at the high level. The outputs will be off when the MUTE pin is at the low level; in particular, the outputs go to the high-impedance state at this time.	MUTE 40kΩ Solve S
29	VREF	Reference voltage input.	VCC GND VCC
16	RESET	Reset output. When REG C (3.3VREG) is high, RESET will be high. When REG C (3.3VREG) is low, RESET will be low. Details of Operating voltage see section Reset operation.	REG_C (3.3VREG) RESET GND GND
17	CD	Reset output delay time setting. The delay time until the point the reset output switches from low to high is set by the capacitor connected between this pin and ground. Reference to Reset operation.	GND CD GND

Application Circuit Example



Reset Operation



- *1: td is the delay time. It is set by an external capacitor connected between the CD pin and ground).
- *2 : The voltage at which RESET changes state is a typical value (voltage).

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